# Autler-Townes spectroscopy in a Mn-doped InAs/GaAs quantum dot

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- Self-assembled InAs/GaAs quantum dot (QD)
- Applications
  - Single photon sources
  - Quantum memories



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- $\odot$  Single Mn dopant (A^0 ) provides a  $|{\pm}1\rangle$  spin state
- Exchange interaction with a confined hole:
  - ferromagnetic  $|\pm 1, \pm \frac{3}{2}\rangle$ , antiferromagnetic configuration  $|\pm 1, \pm \frac{3}{2}\rangle$

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- $_{\odot}$  Optical transitions: Double  $\Lambda$  system

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#### Motivation/Experimental setup

- Coherent probing of these transitions by resonant spectroscopy
- Dark field confocal microscope
- H/V cross-polarized configuration
- Typical laser extinction 10<sup>6</sup>-10<sup>7</sup>





### Optically driven QD near resonance

Strong field light-matter interaction

#### Autler-Townes splitting

 Sufficiently strong resonant driving field -> dressed states

o generalised Rabi frequency  $\Omega_R = \sqrt{\Omega_0^2 + \delta_l^2}$ 

• Scales as  $\Omega_R \sim \sqrt{P}$ 

 $\circ$  Autler-Townes effect observed in  $\Lambda$  system



#### Single-laser probing



- Natural QD linewidth (~1.5 μeV)
- → Spectral diffusion

### Single-laser probing



• What if we increase the power of resonant laser?

o Raman line

 $_{\odot}$  Autler-Townes splitting  $\Omega_{R}$  resolved



#### Single-laser probing



 $_{\rm O}$  Autler-Townes splitting  $\Omega_{R}$  resolved

Ω<sub>R</sub> shows square root power dependence

$$\circ \Omega_R = k\sqrt{P}$$

 $\circ$  Saturation power  $P \sim 1 \ \mu W$ 



• AT splitting probed by second laser

- Fixed strong laser pump
- Scanning laser of lower power probe



o Model that describes this system?

## Model



• Rabi frequencies ( $\Omega = k\sqrt{P}, \ \Omega' = k'\sqrt{P'}$ ) • laser detunings  $\delta, \delta'$ • population decay rate  $\gamma_i$ • pure dephasing rate  $\Gamma_{ij}$ 



- Density matrix equations
- Rotating wave approximation
- Steady-state regime

 $\odot$  Inhomogeneous broadening (assuming Gaussian distribution of (FWHM ~16  $\mu eV))$ 

Numerical solution





Dependence on pump power and pump detuning

• No significant pure dephasing  $(\Gamma_{21} = \Gamma_{23} = \Gamma_{13} = 0 \ \mu eV)$ 

 $\circ \gamma_4$  is small ( $\gamma_1 = 1 \ \mu eV, \gamma_3 = 1.1 \ \mu eV, \gamma_4 = 0.07 \ \mu eV$ )



 $\circ$  Pump laser (11  $\mu$ W), probe laser (1.3  $\mu$ W)

 $_{\odot}$  Dip with typical 10  $\mu eV$  linewidth

 The two-laser resonance reveals the spin coherence of X<sup>+</sup>-A<sup>0</sup> states.





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#### Conclusion and perspectives

- QD in cavity
- $\circ$  For X<sup>+</sup> trion,  $\Gamma_{13}$  is small
- $\odot$  Working with  $X^0$  and  $X^{\scriptscriptstyle -}$  trions
- Coherent population trapping





W. B. Gao, et al., Nature 491, 426–430 (2012)



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